

- ◆Si APN
- ◆RoHS COMPLIANT

## 1. APPLICATION

Fluorescent Lamp、Electronic Ballast、  
and Switch-mode power supplies

## 2. FEATURES

- High voltage capability
- Intergrated antiparallel collector-emitter diode
- Features of good high temperature
- High switching speed

## 3. PACKAGE

TO-220

## 4. Electrical Characteristics

### 4.1 Absolute Maximum Ratings

$T_{amb}=25^{\circ}\text{C}$  unless specified

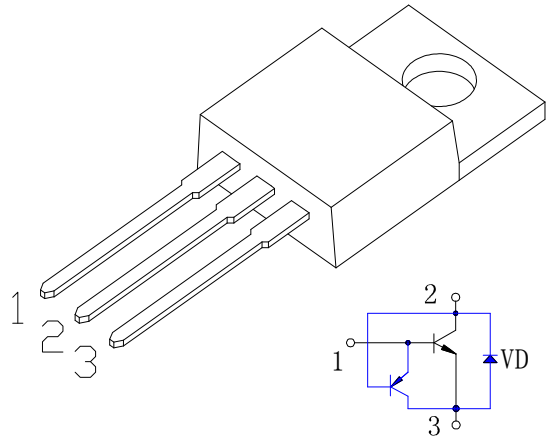
| PARAMETER                 |                          | SYMBOL    | VALUE   | UNIT               |
|---------------------------|--------------------------|-----------|---------|--------------------|
| Collector-Base Voltage    |                          | $V_{CBO}$ | 700     | V                  |
| Collector-Emitter Voltage |                          | $V_{CEO}$ | 400     | V                  |
| Emitter- Base Voltage     |                          | $V_{EBO}$ | 9       | V                  |
| Collector Current         |                          | $I_C$     | 2.3     | A                  |
| Power Dissipation         | $T_a=25^{\circ}\text{C}$ | $P_{tot}$ | 2       | W                  |
|                           | $T_c=25^{\circ}\text{C}$ |           | 30      |                    |
| Junction Temperature      |                          | $T_j$     | 150     | $^{\circ}\text{C}$ |
| Storage Temperature       |                          | $T_{stg}$ | -55~150 | $^{\circ}\text{C}$ |

### 4.2 Electrical Parameter

$T_{amb}=25^{\circ}\text{C}$  unless specified

| PARAMETER                            | SYMBOL                | TEST CONDITION                                       | VALUE |     |     | UNIT          |
|--------------------------------------|-----------------------|--|-------|-----|-----|---------------|
|                                      |                       |  | MIN   | TYP | MAX |               |
| Collector-Base Voltage               | $BV_{CBO}$            | $I_C=1\text{mA}, I_E=0$                              | 700   |     |     | V             |
| Collector-Emitter Voltage            | $BV_{CEO}$            | $I_C=1\text{mA}, I_B=0$                              | 400   |     |     | V             |
| Emitter-Base Voltage                 | $BV_{EBO}$            | $I_E=1\text{mA}, I_C=0$                              | 9     |     |     | V             |
| Collector-Base Cutoff Current        | $I_{CBO}$             | $V_{CB}=700\text{V}, I_E=0$                          |       |     | 10  | $\mu\text{A}$ |
| Collector-Emitter Cutoff Current     | $I_{CEO}$             | $V_{CE}=400\text{V}, I_B=0$                          |       |     | 20  | $\mu\text{A}$ |
| Emitter-Base Cutoff Current          | $I_{EBO}$             | $V_{EB}=9\text{V}, I_C=0$                            |       |     | 10  | $\mu\text{A}$ |
| DC Current Gain                      | $h_{FE}^*$            | $V_{CE}=5\text{V}, I_C=1\text{mA}$                   | 8     |     |     |               |
|                                      |                       | $V_{CE}=5\text{V}, I_C=500\text{mA}$                 | 15    |     | 30  |               |
| Collector-Emitter Saturation Voltage | $V_{CE\text{ sat}}^*$ | $I_C=1\text{A}, I_B=0.5\text{A}$                     |       |     | 0.6 | V             |
| Base-Emitter Saturation Voltage      | $V_{BE\text{ sat}}^*$ | $I_C=1\text{A}, I_B=0.5\text{A}$                     |       |     | 1.2 | V             |
| Rising Time                          | $t_r$                 | $I_C=250\text{mA}$ (UI9600)                          |       |     | 0.8 | $\mu\text{s}$ |
| Falling Time                         | $t_f$                 |  |       |     | 0.8 | $\mu\text{s}$ |
| Storage Time                         | $t_s$                 |  | 2.3   |     | 3.5 | $\mu\text{s}$ |
| Typical Frequency                    | $f_T$                 | $V_{CE}=10\text{V}, I_C=100\text{mA}, f=1\text{MHz}$ | 5     |     |     | MHz           |

\* : Pulse test  $t_p \leq 300 \mu\text{s}, \delta \leq 2\%$



1 Base(B) 2 Collector(C) 3 Emitter(E)

## 5. Characteristic Curve

Fig1 SOA (DC)

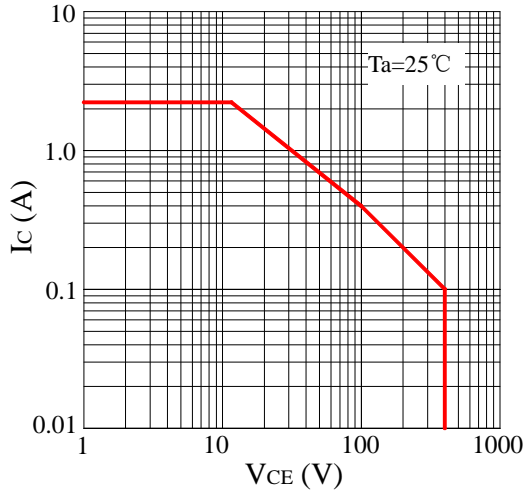


Fig2 Ptot - T

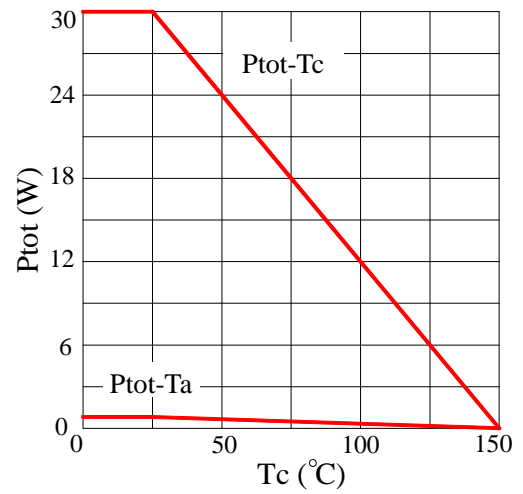


Fig3 Static Characteristic

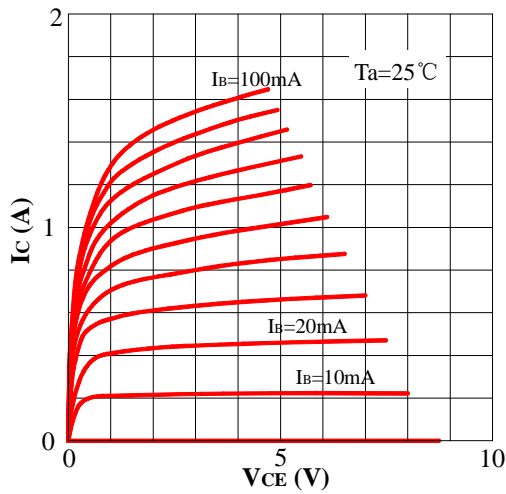


Fig4 hFE-Ic

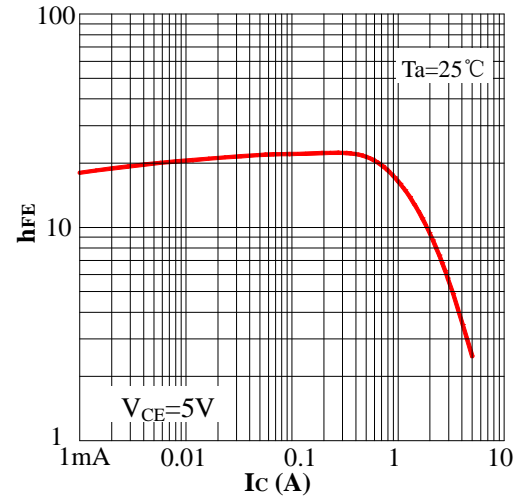


Fig5 VCESat-Ic

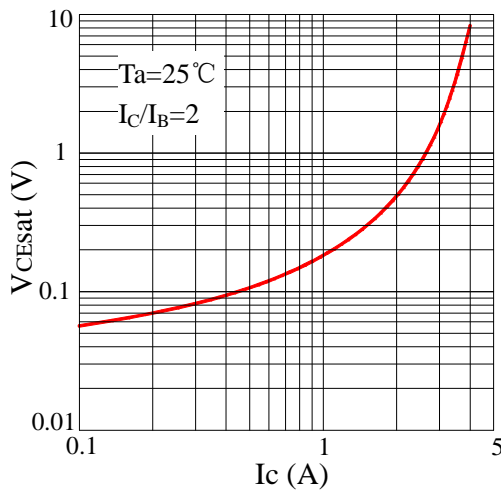
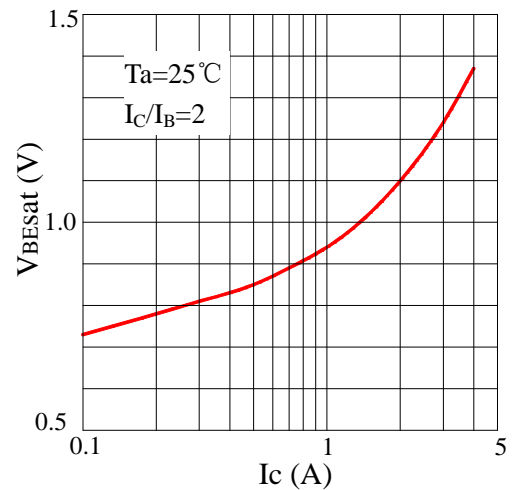


Fig6 VBESat-Ic



## 6. Package Dimentions(Unit: mm)

T0-220

